

Thorium-doping induced superconductivity up to 56 K in $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$

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Following the discovery of superconductivity in an iron-based arsenide $\text{LaO}_{1-x}\text{F}_x\text{FeAs}$ with a superconducting transition temperature (T_c) of 26 K[1], T_c was pushed up surprisingly to above 40 K by either applying pressure[2] or replacing La with Sm[3], Ce[4], Nd[5] and Pr[6]. The maximum T_c has climbed to 55 K, observed in $\text{SmO}_{1-x}\text{F}_x\text{FeAs}$ [7, 8] and SmFeAsO_{1-x} [9]. The value of T_c was found to increase with decreasing lattice parameters in $\text{LnFeAsO}_{1-x}\text{F}_x$ (Ln stands for the lanthanide elements) at an apparently optimal doping level. However, the F^- doping in GdFeAsO is particularly difficult[10, 11] due to the lattice mismatch between the Gd_2O_2 layers and Fe_2As_2 layers. Here we report observation of superconductivity with T_c as high as 56 K by the Th^{4+} substitution for Gd^{3+} in GdFeAsO . The incorporation of relatively large Th^{4+} ions relaxes the lattice mismatch, hence induces the high temperature superconductivity.

LnFeAsO family[12] crystalline in tetragonal ZrCuSiAs -type[13] structure with space group $P4/nmm$. From the crystal chemistry point of view, the crystal structure can be described as an alternate stacking of Ln_2O_2 fluorite-type block layers and Fe_2As_2 antifluorite-type block layers along c -axis. The two block layers are connected by CsCl -type layers (Figure 1). Therefore, the chemical stability of LnFeAsO depends, to some extent, on the lattice match between the two block layers. A rough estimate based on the effective ionic radii[14] indicates that the Ln_2O_2 planar lattice is substantially smaller than the Fe_2As_2 lattice. The lattice mismatch becomes more serious for the LnFeAsO member with a smaller Ln^{3+} ion. That may explain why TbFeAsO , DyFeAsO and other heavy-lanthanide-containing LnFeAsO members were hard to synthesize previously[12].

As the family member with the relatively small Ln^{3+} ion, GdFeAsO is a promising parent compound to have a higher T_c through carrier doping. Similar to cuprate superconductors in which superconductivity emerges when charge carriers are induced into CuO_2 planes by chemical doping at "charge reservoir layers", [15] superconductivity in $\text{LnFeAsO}_{1-x}\text{F}_x$ is realized by partial substitution of O^{2-} with F^- . The F^- -for- O^{2-} substitution introduces extra positive charges in the insulat-

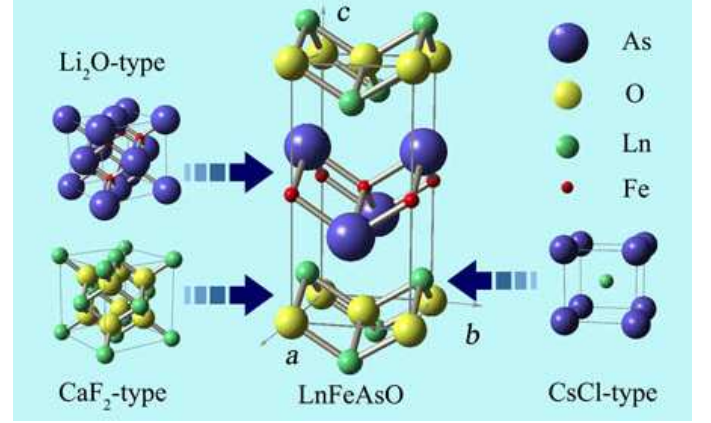


FIG. 1: **Crystal chemistry understanding of the structure of LnFeAsO (Ln =lanthanides).** The stacking of fluorite (CaF_2) layers, CsCl -type layers and antifluorite (Li_2O) layers along c -axis forms the LnFeAsO structure. The lattice constant along the stacking direction can be expressed by the formula $c \simeq \frac{1}{2}a_{\text{CaF}_2} + \frac{1}{2}a_{\text{CsCl}} + \frac{1}{2}a_{\text{Li}_2\text{O}}$, which basically satisfies the experimental result. Note that the lattice mismatch between the Ln_2O_2 layers and the Fe_2As_2 layers affects the chemical stability of LnFeAsO .

ing Ln_2O_2 layers and negative charges (electron doping) in the Fe_2As_2 layers. Earlier preliminary experiment showed sign of superconductivity below 10 K in $\text{GdFeAsO}_{1-x}\text{F}_x$. [10] Later, T_c was pushed up to 36 K in a polycrystalline sample with a nominal composition of $\text{GdO}_{0.83}\text{F}_{0.17}\text{FeAs}$. [11] Very recently the T_c value was increased to 53.5 K in oxygen-deficient GdFeAsO_{1-x} by using high-pressure synthesis. [16] It is of great interest whether the T_c can be elevated further in electron-doped GdFeAsO systems.

Up to now, electron doping in the iron-based oxyarsenides was realized through the chemical substitution only at oxygen site in Ln_2O_2 layers. Because the ionic radius of F^- (1.31 Å, CN=4) is distinctly smaller than that of O^{2-} (1.38 Å, CN=4) [14], F^- substitution for O^{2-} in GdFeAsO leads to more severe lattice mismatch as mentioned above. In other word, doping F^- (or oxygen vacancy) in GdFeAsO is particularly difficult, which is probably the main obstacle to elevate T_c . Substitution of Ln^{3+} by relatively large tetravalence ions is an alternative route to introduce electrons. A successful example was the electron doping in $\text{Ln}_{2-x}\text{Ce}_x\text{CuO}_4$ ($\text{Ln}=\text{Pr}$, Nd or Sm), which has led to the discovery of n -type cuprate superconductors [17]. Th^{4+} is a very stable tetravalence ions and is as large as Gd^{3+} [14], therefore, we pursued the Th^{4+} substitution for Gd^{3+} in the GdFeAsO system.

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Figure 2a shows the X-ray diffraction (XRD) patterns of the $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$ samples. The XRD peaks of the undoped compound can be well indexed based on the tetragonal ZrCuSiAs -type structure, indicating single phase of GdFeAsO . As for the Th-doped samples, small amount of unreacted ThO_2 can be seen. The refined lattice parameters are $a = 3.9154(2)$ Å and $c = 8.4472(4)$ Å for the parent compound, basically consistent with the previously reported values[12]. For the Th-doped sample of $x=0.2$, the fitted lattice parameters are $a = 3.9161(2)$ Å and $c = 8.4386(3)$ Å. The other Th-doped sample of $x=0.25$ has a similar unit cell with $a=3.9166(3)$ Å and $c = 8.4382(5)$ Å. Therefore, it is evident that the Th-doping tends to expand the lattice within ab -planes but to shorten the lattice along the c -axis. The substantial change in cell constants indicates that thorium is incorporated in the lattice. Meanwhile, the ab -plane expansion reflects the effective electron doping onto FeAs layers.

More direct evidence of Th incorporation into the lattice comes from the chemical composition measurement by energy-dispersive X-ray (EDX) microanalysis. Figure 2b shows that the microcrystal in the SEM image contains remarkably Th in addition to Gd, O, Fe and As. Quantitative analysis gives the Gd:Th:Fe:As ratios as 0.83:0.19:0.96:1.00 for the $x=0.2$ sample (Here we omit the oxygen content because the amount of oxygen cannot be measured so precisely by EDX technique). This result demonstrates that most of the Th was successfully doped for the sample of $x=0.2$. Obviously, Th-doping level is higher than that of F-doping in GdFeAsO [10, 11].

Figure 3a shows the $\rho(T)$ curve for $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$ samples. For the undoped GdFeAsO , the $\rho(T)$ curve exhibits an obvious anomaly at 128 K, characterized by a resistivity drop with decreasing temperature. In LaFeAsO a similar resistivity anomaly was found at 150 K,[1, 18] which has been recently suggested to be associated with a structural phase transition and/or an antiferromagnetic spin-density-wave transition[18, 19, 20, 21]. We speculate that the present resistivity anomaly in GdFeAsO has a similar physical origin with that in LaFeAsO . For $x=0.2$ and $x=0.25$, such resistivity anomaly disappears, instead, resistivity drops abruptly to zero below 55 K, indicating a superconducting transition. In addition, the linear temperature-dependence of normal-state resistivity near T_c suggests possible non-Fermi liquid behavior in the present system, similar to that in $\text{SmFeAsO}_{1-x}\text{F}_x$ [8].

The magnetic measurement on $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$ samples was shown in Figure 3b. In the parent compound, the high-temperature magnetic susceptibility (χ) follows the Curie-Weiss law. The fitted effective magnetic moments was $7.96 \mu_B$ per formula unit, in good agreement with the magnetic moment of free Gd^{3+} ion. Below 4.2 K, χ drops sharply, indicating an antiferromagnetic ordering of Gd^{3+} magnetic moments. Note that similar behavior was observed in SmFeAsO where the Neel temperature was 4.6 K.[22]

For the Th-doped samples, e.g., $x=0.2$, the normal-

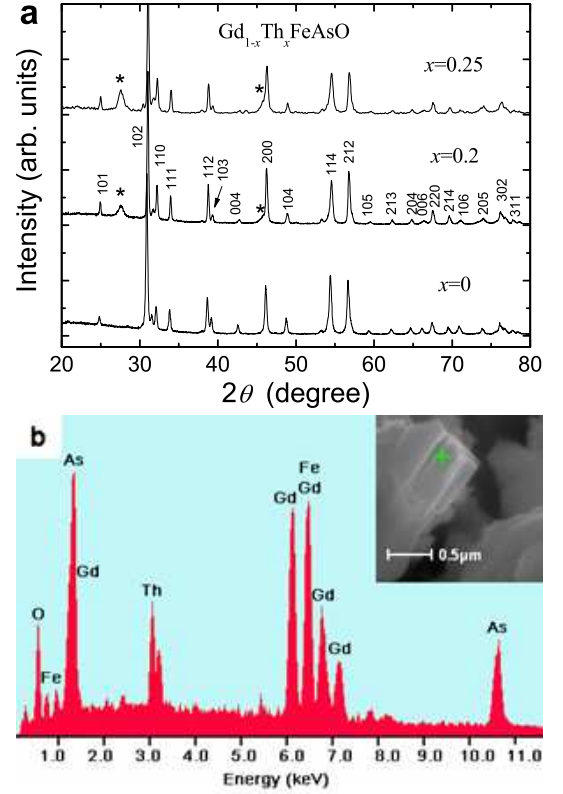


FIG. 2: **Phase and compositional analysis of $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$ samples.** **a**, Powder XRD of $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$ polycrystalline samples. The asterisked peaks come from unreacted ThO_2 . **b**, a representative EDX spectrum of a crystalline grain of $\text{Gd}_{0.8}\text{Th}_{0.2}\text{FeAsO}$ sample, indicating the incorporation of thorium into the lattice. The inset shows the SEM image of the identical sample. The marked spot is the position where the EDX spectrum was collected.

state susceptibility roughly obeys Curie-Weiss law. Below 55 K, χ drops steeply to negative values, confirming the superconductivity observed above. After subtracting the paramagnetic susceptibility of Gd^{3+} ions, the volume fraction of magnetic shielding at 10 K was estimated to be over 50%, indicating bulk superconductivity. The differential χ_{FC} curve in the inset of Figure 3b shows that the $T_c(\text{onset})$ is over 56 K, consistent with the resistance measurement. Therefore, Th-doping in GdFeAsO elevates the T_c by 20 K ($T_c=36$ K in $\text{GdO}_{0.83}\text{F}_{0.17}\text{FeAs}$ [11]). Moreover, the T_c of 56 K is among the highest ever discovered in iron-based oxypnictides.

Our observation of superconductivity in $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$ indicates that the Ln-site substitution in LnFeOAs is feasible to realize electron doping, hence the high temperature superconductivity. Moreover, the electron-doping is more easily induced by the Th^{4+} -substitution compared with the F^- -substitution in GdFeOAs . This manifests that the lattice match between Ln_2O_2 fluorite-type layers and Fe_2As_2 antiferrotype layers is important not only for the chemical stability of

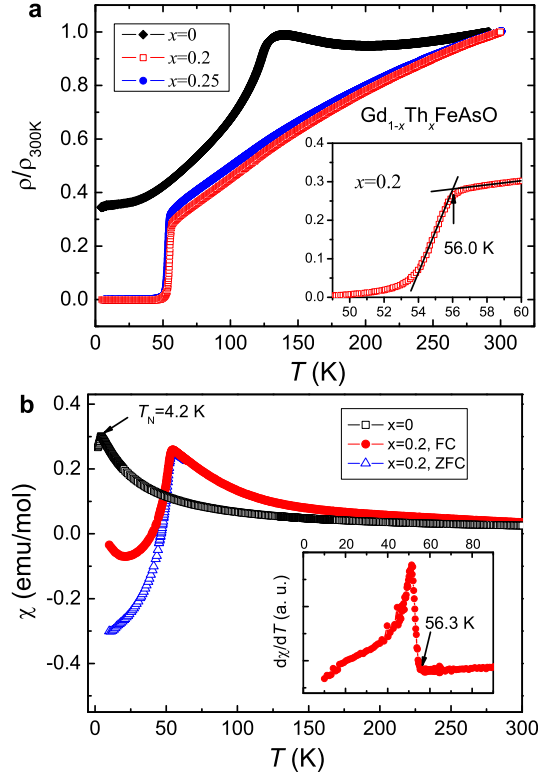


FIG. 3: **Electrical resistivity (ρ) and magnetic susceptibility (χ) of $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$.** **a**, ρ versus T . The data are normalized to $\rho_{300\text{K}}$ as the resistivity measured on polycrystalline samples is often higher than the intrinsic value due to the grain boundary and surface effect. The inset is an expanded plot to show the superconducting transition at 56 K for the sample of $x=0.2$. **b**, χ versus T . The lower inset shows the differential χ_{FC} curve of $\text{Gd}_{0.8}\text{Th}_{0.2}\text{FeAsO}$ powder sample, which locates the onset T_c at 56.3 K. ZFC, zero-field cooling; FC, field cooling.

the parent compounds, but also for the electron-doping level in LnFeAsO . It is thus expected that the thorium-doping strategy can be applied to other iron-based oxypnictides.

METHODS

Sample preparation

Polycrystalline samples of $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$ were synthesized by solid state reaction in an evacuated quartz

tube. All the starting materials (Gd , Gd_2O_3 , ThO_2 , Fe and As) are with high purity ($\geq 99.95\%$). First, GdAs was presynthesized by reacting Gd tapes with As pieces in vacuum at 773 K for 10 hours and then 1173 K for 12 hours. Similarly, FeAs was prepared by reacting Fe powders with As shots at 773 K for 6 hours and then 1030 K for 12 hours. Then, powders of GdAs , Gd_2O_3 , ThO_2 , Fe and FeAs were weighed according to the stoichiometric ratio of $\text{Gd}_{1-x}\text{Th}_x\text{FeAsO}$. The weighed powders were mixed thoroughly by grinding, and pressed into pellets under a pressure of 4000 kg/cm^2 in an argon-filled glove box. The pressed pellets were wrapped with Ta foils, and sealed in an evacuated quartz ampoule. The sealed ampoule was slowly heated to 1423 K, holding for 48 hours. Finally the samples were rapidly cooled to room temperature.

Structural characterizations

Powder X-ray diffraction was performed at room temperature using a D/Max-rA diffractometer with $\text{Cu K}\alpha$ radiation and a graphite monochromator. The XRD diffractometer system was calibrated using standard Si powders. Lattice parameters were refined by a least-squares fit using at least 20 XRD peaks. Energy-dispersive X-ray (EDX) spectra were obtained by using the Phoenix EDAX equipment attached to a field-emission scanning electron microscope (SIRION FEI). The ground sample powders were placed directly on the copper sample holder for making the SEM specimen.

Electrical and magnetic measurements

The electrical resistivity was measured with a standard four-terminal method. Samples were cut into a thin bar with typical size of $4\text{mm} \times 2\text{mm} \times 0.5\text{mm}$. Gold wires were attached onto the samples' newly-abraded surface with silver paint. The size of the contact pads leads to a total uncertainty in the absolute values of resistivity of 10 %. The electrical resistance was measured using a steady current of 5 mA, after checking the linear $I - V$ characteristic.

Temperature dependence of magnetization was measured on a Quantum Design Magnetic Property Measurement System (MPMS-5). For the measurement of the undoped compound, the applied field was 1000 Oe. For the measurement of the Th-doped superconducting samples, both the zero-field-cooling and field-cooling protocols were employed under the field of 10 Oe.

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